

Photocouplers GaAs Infrared LED & Photo Triac

TLP265J

1. Applications

- · Triac Drivers
- Programmable Logic Controllers (PLCs)
- · AC-Output Modules
- · Solid-State Relays

2. General

The TLP265J consists of a non zero crossing photo triac, optically coupled to a gallium arsenide infrared emitting diode. The TLP265J is housed in the SO6 package and guarantees a creepage distance of $5.0 \, \text{mm}$ (min), a clearance of $5.0 \, \text{mm}$ (min) and insulation thickness of $0.4 \, \text{mm}$ (min). Therefore, the TLP265J meets the reinforced insulation class requirements of international safety standards.

3. Features

(1) Peak off-state voltage: 600 V (min)

(2) Non zero crossing functionary (NZC)

(3) Trigger LED current: 10 mA (max)

(4) On-state current: 70 mA (max)

(5) Isolation voltage: 3750 Vrms (min)

(6) Safety standards

UL-approved: UL1577 File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A, File No.E67349

VDE-approved: Option (V4) EN60747-5-5 (**Note**) Maximum operating insulation voltage: 707 Vpeak Highest permissible overvoltage: 6000 Vpeak

Note: When an EN60747-5-5 approved type is needed, please designate the **Option (V4)**.

Table Trigger LED Current (Note) (Unless otherwise specified, T_a = 25 °C)

Rank	I _{FT} Rank Marking	Test Condition	Trigger LED Current I _{FT} (min)	Trigger LED Current I _{FT} (max)	Unit
None	10	V _T = 6 V	_	10	mA
(IFT7)	7	V _T = 6 V	_	7	

Note: Specify both the part number and a rank in this format when ordering.

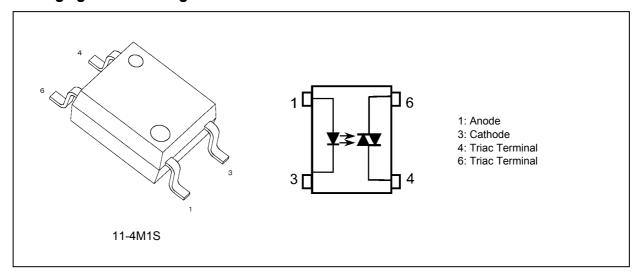
Example: TLP265J (IFT7)

For safety standard certification, however, specify the part number alone.

Example: TLP265J



4. Packaging and Pin Assignment



5. Mechanical Parameters

Characteristics	2.54-mm pitch	Unit
Creepage distances	5.0 (min)	mm
Clearance distances	5.0 (min)	
Internal isolation thickness	0.4 (min)	



6. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		30	mA
	Input forward current derating	(T _a ≥ 53 °C)	$\Delta I_F/\Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	1	Α
	Input reverse voltage		V _R		5	V
	Junction temperature		Tj		125	°C
	Input power dissipation		P_{D}		50	mW
Detector	Off-state output terminal voltage		V_{DRM}		600	V
	R.M.S. on-state current	(T _a = 25 °C)	I _{T(RMS)}		70	mA
	R.M.S. on-state current	(T _a = 70 °C)	I _{T(RMS)}		40]
	R.M.S. on-state current derating	(T _a ≥ 25 °C)	$\Delta I_{T(RMS)}/\Delta T_a$		-0.67	mA/°C
	ON-state current (pulsed)		I _{ONP}	(Note 2)	2	Α
	Peak non-repetitive surge current		I _{TSM}	(Note 3)	1.2	Α
	Junction temperature		Tj		125	°C
	Input power dissipation		P_{D}		200	mW
Common	Operating temperature		T _{opr}		-40 to 100	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	AC, 1 min, R.H. ≤ 60 %	BV _S	(Note 4)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 100 μ s, 100 pps

Note 2: Pulse width (PW) \leq 100 μ s, 120 pps

Note 3: Pulse width (PW) \leq 10 ms

Note 4: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4 and 6 are shorted together.

7. Recommended Operating Conditions (Note)

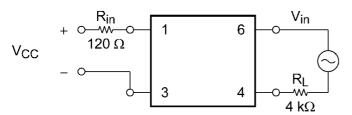
Characteristics	Symbol	Note	Min	Тур.	Max	Unit
AC mains voltage	V _{AC}		_		240	V
Input forward current	I _F		15	20	25	mA
ON-state current (pulsed)	I _{ONP}		_	_	1	Α
Operating temperature	T _{opr}		-25	_	85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.



8. Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.0	1.27	1.4	V
	Input reverse current	I _R		V _R = 5 V	_	_	10	μА
	Input capacitance	Ct		V = 0 V, f = 1 MHz	_	30	_	pF
Detector	Peak off-state current	I _{DRM}		V _{DRM} = 600 V	_	10	1000	nA
	Peak on-state voltage	V _{TM}		I _{TM} = 70 mA	_	1.7	2.8	V
	Holding current	ΙH		_	_	1.0	_	mA
	Critical rate of rise of off-state voltage	dv/dt		V _{in} = 240 V, T _a = 85 °C See Fig. 8.1	_	500		V/μs
	Critical rate of rise of commutating voltage (dv/dt)	dv/dt(c)		V_{in} = 60 Vrms, I_T = 15 mA See Fig. 8.1	_	0.2	_	



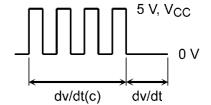


Fig. 8.1 dv/dt Test Circuit

9. Coupled Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		V _T = 6 V	_	_	10	mA
Turn-on time	t _{on}		V_D = 6 \rightarrow 4 V, R_L = 100 Ω , I_F = Rated $I_{FT} \times 1.5$ mA			100	μS

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		0.8		pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60%	1 × 10 ¹²	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 1 min.	3750	_	_	Vrms
			AC, 1 s in oil		10000	_	
			DC, 1 min. in oil	_	10000		Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4 and 6 are shorted together.

11. Characteristics Curves (Note)

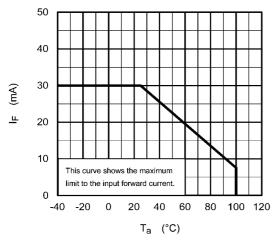


Fig. 11.1 I_F - T_a

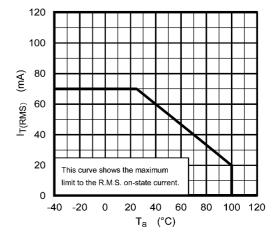


Fig. 11.2 I_{T(RMS)} - T_a

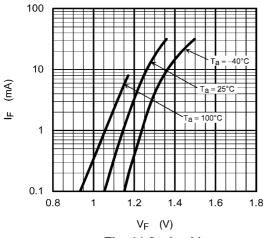


Fig. 11.3 I_F - V_F

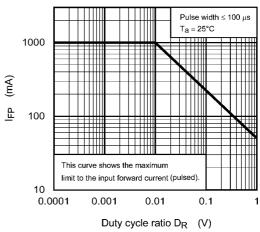


Fig. 11.4 I_{FP} - D_R

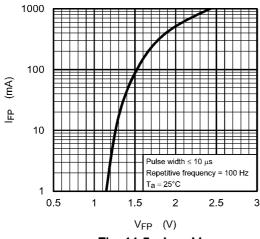


Fig. 11.5 IFP - VFP

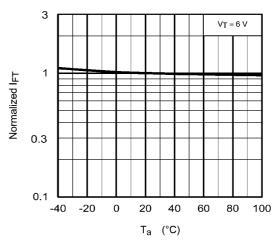


Fig. 11.6 Normalized IFT - Ta

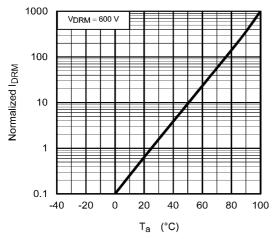


Fig. 11.7 Normalized I_{DRM} - T_a

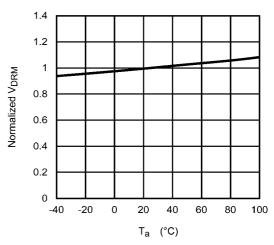


Fig. 11.8 Normalized V_{DRM} - T_a

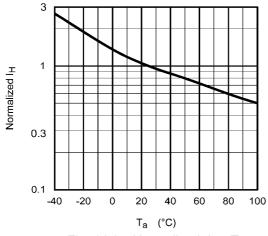


Fig. 11.9 Normalized I_H - T_a

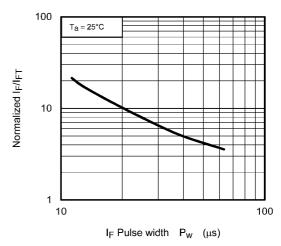


Fig. 11.10 Normalized I_F/I_{FT} - I_F_P_W

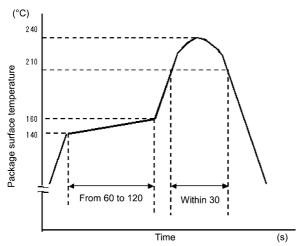
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

12. Soldering and Storage

12.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

When using soldering reflow (See Fig. 12.1.1 and 12.1.2)
 Reflow soldering must be performed once or twice.
 The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



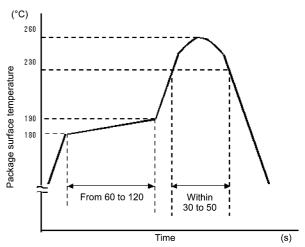


Fig. 12.1.1 An Example of a Temperature Profile When Sn-Pb Eutectic Solder Is Used

Fig. 12.1.2 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

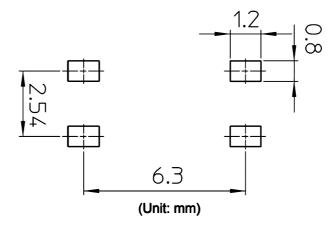
- When using soldering flow (Applicable to both eutectic solder and Lead(Pb)-Free solder)
 Apply preheating of 150 °C for 60 to 120 seconds.
 Mounting condition of 260 °C within 10 seconds is recommended.
 - Flow soldering must be performed once.
- When using soldering Iron (Applicable to both eutectic solder and Lead(Pb)·Free solder)
 Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C Heating by soldering iron must be done only once per lead.

12.2. Precautions for General Storage

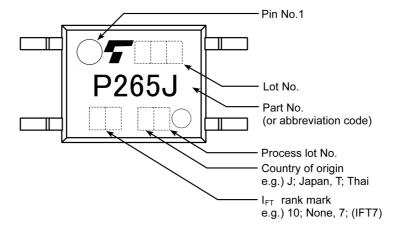
- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45% to 75%, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



13. Land Pattern Dimensions (for reference only)



14. Marking (Note)



Note: A different marking is used for photocouplers that have been qualified according to option (V4) of EN60747. See Fig.15.4.



15. EN60747-5-5 Option (V4) Specification

· Part number: TLP265J (Note)

• The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN60747.

Example: TLP265J(V4-TPL, E(O

V4: EN60747 option TPL: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 1)

Note: Use TOSHIBA standard type number for safety standard application.

e.g., TLP265J(V4) \rightarrow TLP265J

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

Descri	otion	Symbol	Rating	Unit
Application classification for rated mains voltage ≤ 150 Vrms for rated mains voltage ≤ 300 Vrms		I-IV I-III	_	
Climatic classification		40 / 125 / 21	_	
Pollution degree		2	_	
Maximum operating insulation voltage	Viorm	707	Vpk	
Input to output test voltage, Method A V_{pr} = 1.5 × V_{IORM} , type and sample t_p = 10 s, partial discharge < 5 pC	V _{pr}	1060	Vpk	
Input to output test voltage, Method B $V_{pr} = 1.875 \times V_{IORM}, \ 100\% \ production \ test$ $t_p = 1 \ s, \ partial \ discharge < 5 \ pC$			1325	Vpk
Highest permissible overvoltage (transient overvoltage, t _{pr} = 60 s)	VTR	6000	Vpk	
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current I_F , P_{SO} = 0) power (output or total power dissipation) temperature			250 400 150	mA mW °C
Insulation resistance, input-output	V_{IO} = 500 V, T_a = 25°C V_{IO} = 500 V, T_a = 125°C V_{IO} = 500 V, T_a = T_s	R _{si}	≥ 10 ¹² ≥ 10 ¹¹ ≥ 10 ⁹	Ω

Fig. 15.1 EN60747 Insulation Characteristics



Minimum creepage distance	Cr	5.0 mm
Minimum clearance	Cl	5.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	CTI	175

Fig. 15.2 Insulation Related Specifications (Note)

Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e. g., at a standard distance between soldering eye centers of 3.5 mm). If this is not permissible, the user shall take suitable measures.

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data.

Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 15.3 Marking on packing for EN60747

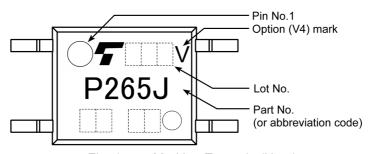
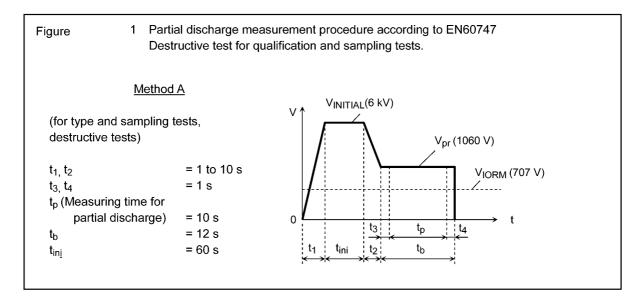
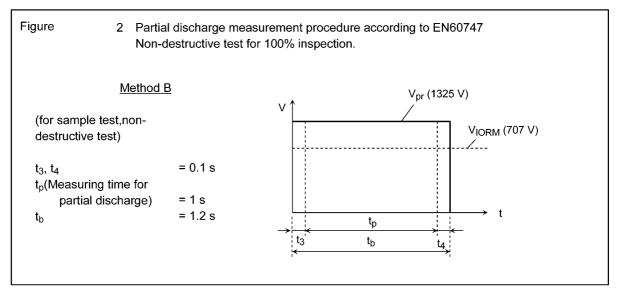


Fig. 15.4 Marking Example (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (V4) of EN60747.





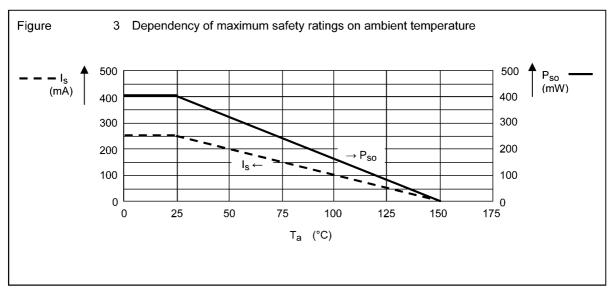
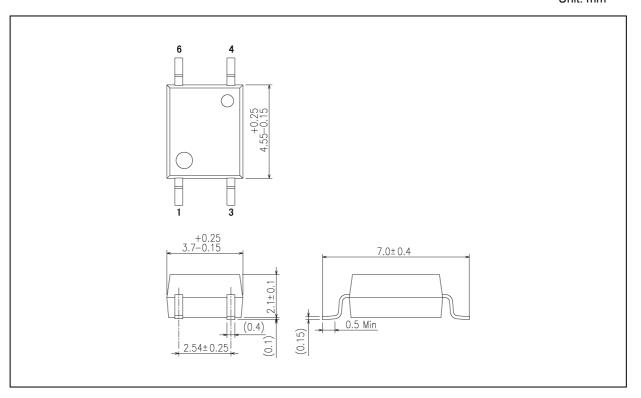


Fig. 15.6 Measurement Procedure



Package Dimensions

Unit: mm



Weight: 0.08 g (typ.)

	Package Name(s)
TOSHIBA: 11-4M1S	



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